

### Discrete POWER & Signal **Technologies**

2N3390 2N3391 2N3391A 2N3392 2N3393



## NPN General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300 mA. Sourced from Process 10. See PN100A for characteristics.

### **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CEO}$	Collector-Emitter Voltage	25	V
V <sub>CBO</sub>	Collector-Base Voltage	25	V
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V
I <sub>C</sub>	Collector Current - Continuous	500	mA
T <sub>J</sub> , T <sub>Sta</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### **Thermal Characteristics**

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		2N3390 / 3391/A / 3392 / 3393	
P <sub>D</sub>	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

# NPN General Purpose Amplifier (continued)

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TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage*	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	25		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 10 \mu A, I_E = 0$	25		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	5.0		V
I <sub>CBO</sub>	Collector-Cutoff Current	$V_{CB} = 18 \text{ V}, I_E = 0$		100	nA
I <sub>EBO</sub>	Emitter-Cutoff Current	$V_{EB} = 5.0 \text{ V}, I_{C} = 0$		100	nA

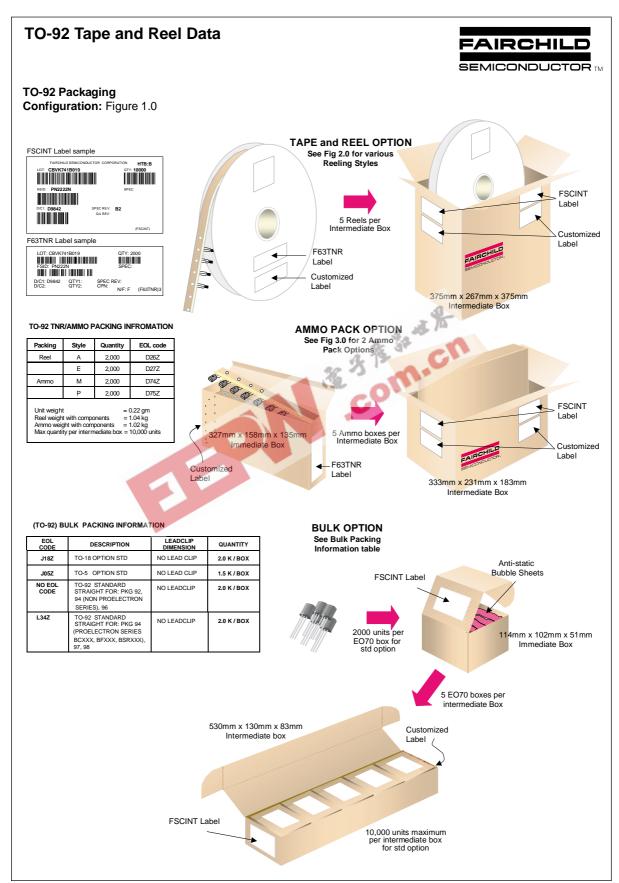
### ON CHARACTERISTICS\*

h <sub>FE</sub>	DC Current Gain	$V_{CE} = 4.5 \text{ V}, I_{C} = 2.0 \text{ mA}$			
		2N3390	400	800	
		2N3391/A	250	500	
		2N3392	150	300	
		2N3 <b>3</b> 93	90	180	

### SMALL SIGNAL CHARACTERISTICS

C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10 V, f = 1.0 MHz	2.0	10	pF
h <sub>fe</sub>	Small-Signal Current Gain	I <sub>C</sub> = 2.0 mA, V <sub>CE</sub> = 4.5 V, f = 1.0 kHz 2N3390 2N3391/A 2N3392 2N3393	400 250 150 90	1250 800 500 400	
NF	Noise Figure	$V_{CE} = 4.5 \text{ V}, I_{C} = 100 \mu\text{A}, \\ R_{G} = 500 \Omega, \qquad \text{2N3391A only} \\ B_{W} = 15.7 \text{ kHz}$		5.0	dB

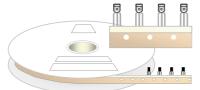
<sup>\*</sup>Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%



### TO-92 Tape and Reel Data, continued

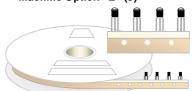
### **TO-92 Reeling Style** Configuration: Figure 2.0

Machine Option "A" (H)



Style "A", D26Z, D70Z (s/h)

Machine Option "E" (J)



Style "E", D27Z, D71Z (s/h)

### **TO-92 Radial Ammo Packaging**

Configuration: Figure 3.0

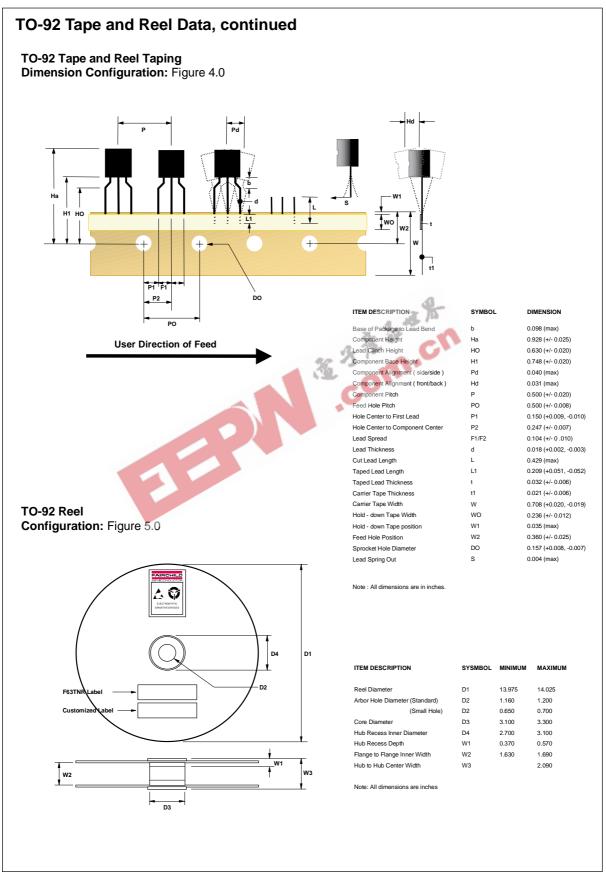


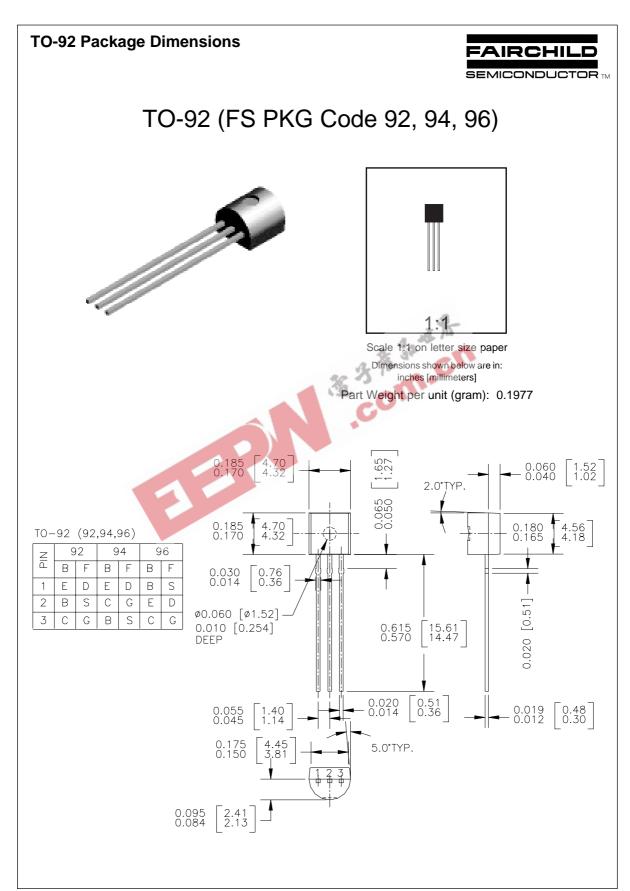
FIRST WIRE OFF IS EMITTER (ON PKG. 92) ADHESIVE TAPE IS ON BOTTOM SIDE FLAT OF TRANSISTOR IS ON BOTTOM

FIRST WIRE OFF IS EMITTER ADHESIVE TAPE IS ON THE TOP SIDE FLAT OF TRANSISTOR IS ON BOTTOM



FIRST WIRE OFF IS COLLECTOR (ON PKG. 92) ADHESIVE TAPE IS ON BOTTOM SIDE FLAT OF TRANSISTOR IS ON TOP





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